IN THE CLAIMS:

The following is a complete listing of the pending claims:

Claims 1 - 5. (cancelled)

6. (currently amended) A stacked inductor comprising:

a semiconductor substrate;

a plurality of conductive layers formed on the substrate, the plurality of

conductive layers being arranged from a first conductive layer closest to the substrate to a

last conductive layer furthest from the substrate; and

a plurality of conductive spirals corresponding to the plurality of conductive layers such that a first spiral is formed in the corresponding first conductive layer, a second spiral is formed in the corresponding second conductive layer, and so on, wherein each spiral includes at least two concentric turns coiled from a first end at an outer radius of the spiral to a second end at an inner radius of the spiral; wherein the first end of the first spiral forms a first port for the inductor, a second end of the first spiral couples through a first via to the second end of the second spiral, the first end of the second spiral couples though a second via to the first end of the third spiral, and so on such that the second end of the next-to-last spiral couples through a last via to the second end of the last spiral, the first end of the inductor

a first spiral inductor of at least two concentric turns having a first end at an outer radius of said spiral and a second end at an inner radius of said spiral on a first layer of a substrate; and

Appl. No. 10/718,501

a-second spiral inductor having a first end at an inner radius of said spiral and a second end at an outer radius of said spiral on a second layer of said substrate;

said-first end of said second spiral inductor electrically coupled to said second and of said first spiral inductor through a via disposed between the first and second layers.

- 7. (currently amended) The stacked inductor of Claim 6, wherein each turn of each spiral comprises five or more linear segments further comprising a third spiral inductor having a first end at an outer radius of said spiral and a second end at an inner radius of said spiral on a third layer of said substrate, wherein said second end of said second spiral inductor electrically coupled to said first end of said third spiral inductor.
- 8. (currently amended) The stacked inductor of Claim 6, wherein said first and second spiral inductors each spiral has a have thickness of between 1 and to 4 μm.
- 9. (currently amended) The stacked inductor of Claim 6, wherein said-first and second each spiral inductors comprise comprises a conductive metal taken from the group consisting of Cu, Al and alloys thereof.
- 10. (currently amended) The stacked inductor of Claim 7, wherein the number of linear segments equals eight A stacked inductor comprising:

a substrate; and

a plurality of planer spiral shaped inductors having a first-ond and a second end, each planer spiral shaped inductor disposed on a different layer of said substrate;

Page 4 of 9

Appl. No. 10/718,501

a first end of each of said planer spiral-shaped inductors electrically coupled to a second of another planer spiral shaped inductors disposed on an adjacent layer.

11. (currently amended) The stacked inductor of Claim 6 10, wherein the first port is coupled to a power supply said-plurality of planer spiral shaped inductors comprises spiral-inductors formed into concentric shapes of at least two turns, wherein each turn includes at least five straight segments.

Claims 12 - 16. (cancelled)